

# MC74LCXU04

## Advance Information

# Low-Voltage CMOS Unbuffered Hex Inverter

## With 5 V-Tolerant Inputs

The MC74LCXU04 is a high performance unbuffered hex inverter operating from a 2.3 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A  $V_I$  specification of 5.5 V allows MC74LCXU04 inputs to be safely driven from 5 V devices.

Current drive capability is 24 mA at the outputs.

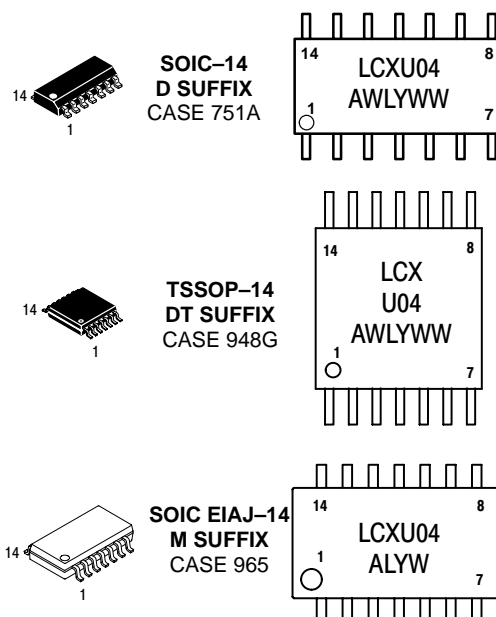
- Designed for 2.3 to 3.6 V  $V_{CC}$  Operation
- 5 V Tolerant Inputs — Interface Capability With 5 V TTL Logic
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current (10  $\mu$ A) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V; Machine Model >200 V



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### MARKING DIAGRAMS



A = Assembly Location  
WL, L = Wafer Lot  
Y = Year  
WW, W = Work Week

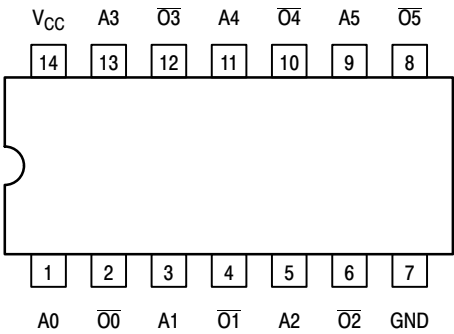
### ORDERING INFORMATION

Device	Package	Shipping
MC74LCXU04D	SOIC-14	55 Units/Rail
MC74LCXU04DR2	SOIC-14	2500 Units/Reel
MC74LCXU04DT	TSSOP-14	96 Units/Rail
MC74LCXU04DTR2	TSSOP-14	2500 Units/Reel
MC74LCXU04M	SOIC EIAJ-14	50 Units/Rail
MC74LCXU04MEL	SOIC EIAJ-14	2000 Units/Reel

This document contains information on a new product. Specifications and information herein are subject to change without notice.

MC74LCXU04

Pinout: 14-Lead (Top View)



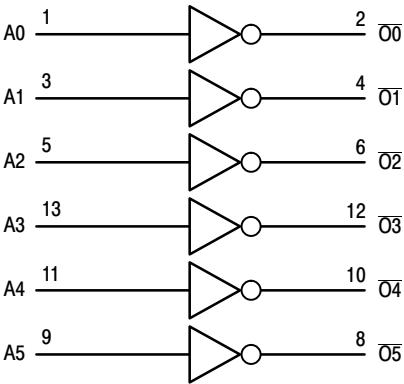
PIN NAMES

Pins	Function
An $\overline{O}n$	Data Inputs Outputs

FUNCTION TABLE

An	$\overline{O}n$
L	H
H	L

LOGIC DIAGRAM



# MC74LCXU04

## ABSOLUTE MAXIMUM RATINGS\*

Symbol	Parameter	Value	Condition	Unit
$V_{CC}$	DC Supply Voltage	-0.5 to +7.0		V
$V_I$	DC Input Voltage	$-0.5 \leq V_I \leq +7.0$		V
$V_O$	DC Output Voltage	$-0.5 \leq V_O \leq V_{CC} + 0.5$	Note 1.	V
$I_{IK}$	DC Input Diode Current	-50	$V_I < GND$	mA
$I_{OK}$	DC Output Diode Current	-50	$V_O < GND$	mA
		+50	$V_O > V_{CC}$	mA
$I_O$	DC Output Source/Sink Current	$\pm 50$		mA
$I_{CC}$	DC Supply Current Per Supply Pin	$\pm 100$		mA
$I_{GND}$	DC Ground Current Per Ground Pin	$\pm 100$		mA
$T_{STG}$	Storage Temperature Range	-65 to +150		°C

\* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

1. Output in HIGH or LOW State.  $I_O$  absolute maximum rating must be observed.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Unit
$V_{CC}$	Supply Voltage Operating Data Retention Only	2.0 1.5	2.3 to 3.3	3.6 3.6	V
$V_I$	Input Voltage	0		5.5	V
$V_O$	Output Voltage (HIGH or LOW State)	0		$V_{CC}$	V
$I_{OH}$	HIGH Level Output Current $V_{CC} = 3.0V - 3.6V$ $V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$			- 24 - 12 - 8	mA
$I_{OL}$	LOW Level Output Current $V_{CC} = 3.0V - 3.6V$ $V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$			+ 24 + 12 + 8	mA
$T_A$	Operating Free-Air Temperature	-40		+85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate, $V_{IN}$ from 0.8V to 2.0V, $V_{CC} = 3.0V$	0		10	ns/V

# MC74LCXU04

## DC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Condition	T <sub>A</sub> = -40°C to +85°C		Unit
			Min	Max	
V <sub>IH</sub>	HIGH Level Input Voltage (Note 2.)	V <sub>CC</sub> = 2.3V V <sub>CC</sub> = 2.7V V <sub>CC</sub> = 3.0V V <sub>CC</sub> = 3.6V	1.8 1.9 2.3 2.8		V
V <sub>IL</sub>	LOW Level Input Voltage (Note 2.)	V <sub>CC</sub> = 2.3V V <sub>CC</sub> = 2.7V V <sub>CC</sub> = 3.0V V <sub>CC</sub> = 3.6V		0.5 0.6 0.5 0.5	V
V <sub>OH</sub>	HIGH Level Output Voltage	2.3V ≤ V <sub>CC</sub> ≤ 3.6V; I <sub>OH</sub> = -100μA V <sub>CC</sub> = 2.3V; I <sub>OH</sub> = -8mA V <sub>CC</sub> = 2.7V; I <sub>OH</sub> = -12mA V <sub>CC</sub> = 3.0V; I <sub>OH</sub> = -24mA	V <sub>CC</sub> - 0.2 1.7 2.1 2.2		V
V <sub>OL</sub>	LOW Level Output Voltage	2.3V ≤ V <sub>CC</sub> ≤ 3.6V; I <sub>OL</sub> = 100μA V <sub>CC</sub> = 2.3V; I <sub>OL</sub> = 8mA V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 12mA V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 24mA		0.2 0.6 0.6 0.6	V
I <sub>I</sub>	Input Leakage Current	2.3V ≤ V <sub>CC</sub> ≤ 3.6V; 0V ≤ V <sub>I</sub> ≤ 5.5V		±5.0	μA
I <sub>CC</sub>	Quiescent Supply Current	2.3V ≤ V <sub>CC</sub> ≤ 3.6V; V <sub>I</sub> = V <sub>CC</sub> or GND 2.3V ≤ V <sub>CC</sub> ≤ 3.6V; 3.6V ≤ V <sub>I</sub> ≤ 5.5V		10 ±10.0	μA
ΔI <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	2.3V ≤ V <sub>CC</sub> ≤ 3.6V, One Input at V <sub>IH</sub> = V <sub>CC</sub> - 0.6		500	μA

2. These values of V<sub>I</sub> are used to test DC electrical characteristics only.

## AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Waveform	Limits						Unit
			T <sub>A</sub> = −40°C to +85°C						
			V <sub>CC</sub> = 3.0 V to 3.6 V		V <sub>CC</sub> = 2.7 V	V <sub>CC</sub> = 2.3 V to 2.7 V			
			C <sub>L</sub> = 50 pF		C <sub>L</sub> = 50 pF	C <sub>L</sub> = 30 pF			
			Min	Max	Max	Min	Max		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Input to Output	1	1 1	3.8 3.8	4.7 4.7	1 1	6.7 6.7	ns	
t <sub>OSHL</sub> t <sub>OSLH</sub>	Output-to-Output Skew (Note 3.)			1.0 1.0				ns	

3. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

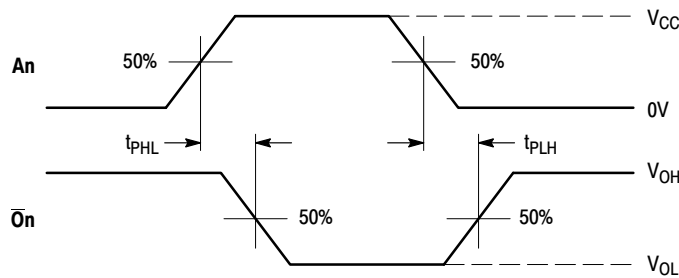
# DYNAMIC SWITCHING CHARACTERISTICS

Symbol	Characteristic	Condition	$T_A = +25^{\circ}\text{C}$			Unit
			Min	Typ	Max	
$V_{OLP}$	Dynamic LOW Peak Voltage (Note 4.)	$V_{CC} = 3.3\text{V}$ , $C_L = 50\text{pF}$ , $V_{IH} = 3.3\text{V}$ , $V_{IL} = 0\text{V}$		0.8		V
$V_{OLV}$	Dynamic LOW Valley Voltage (Note 4.)	$V_{CC} = 3.3\text{V}$ , $C_L = 50\text{pF}$ , $V_{IH} = 3.3\text{V}$ , $V_{IL} = 0\text{V}$		0.8		V

4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

# CAPACITIVE CHARACTERISTICS

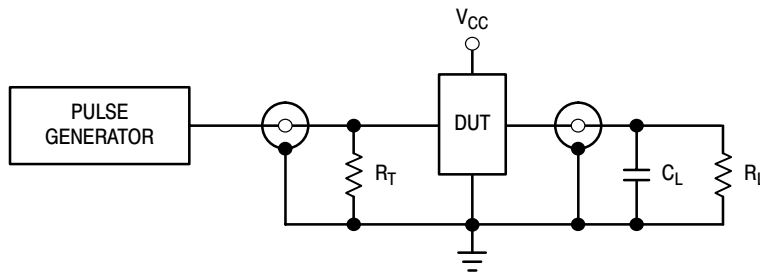
Symbol	Parameter	Condition	Typical	Unit
$C_{IN}$	Input Capacitance	$V_{CC} = 3.3\text{V}$ , $V_I = 0\text{V}$ or $V_{CC}$	7	pF
$C_{OUT}$	Output Capacitance	$V_{CC} = 3.3\text{V}$ , $V_I = 0\text{V}$ or $V_{CC}$	8	pF
$C_{PD}$	Power Dissipation Capacitance	10MHz, $V_{CC} = 3.3\text{V}$ , $V_I = 0\text{V}$ or $V_{CC}$	25	pF



## PROPAGATION DELAYS

$t_R = t_F = 2.5\text{ns}$ , 10% to 90%;  $f = 1\text{MHz}$ ;  $t_W = 500\text{ns}$

Figure 1. AC Waveforms



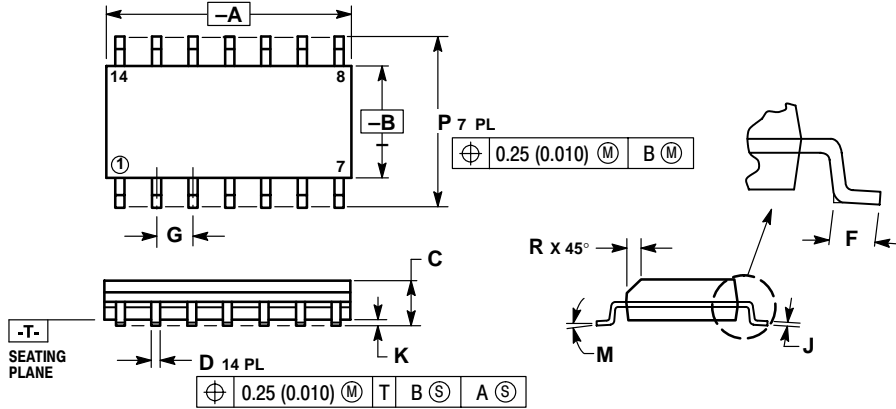
$C_L = 50\text{pF}$  or equivalent (Includes jig and probe capacitance)  
 $R_L = R_1 = 500\Omega$  or equivalent  
 $R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

Figure 2. Test Circuit

# MC74LCXU04

## PACKAGE DIMENSIONS

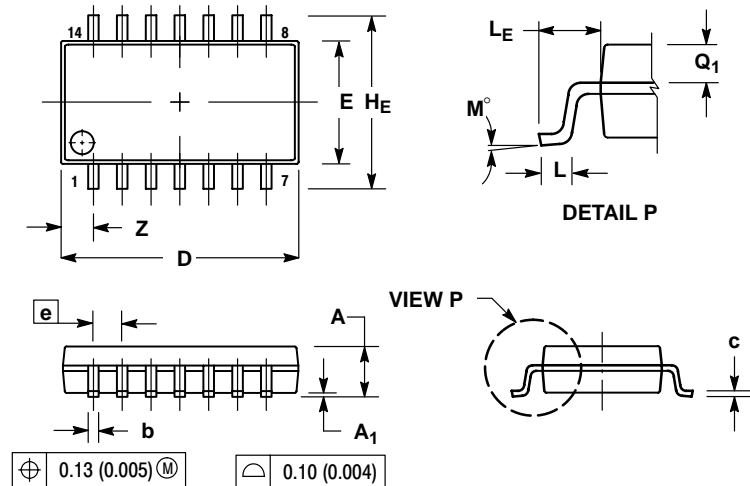
SOIC-14  
D SUFFIX  
CASE 751A-03  
ISSUE F



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

SOIC EIAJ-14  
M SUFFIX  
CASE 965-01  
ISSUE O



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
  5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).


DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H <sub>E</sub>	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L <sub>E</sub>	1.10	1.50	0.043	0.059
M	0°	10°	0°	10°
Q <sub>1</sub>	0.70	0.90	0.028	0.035
Z	---	1.42	---	0.056

## PACKAGE DIMENSIONS

**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAF FLASH OR PROTRUSION. INTERLEAF FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	----	1.20	----	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

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